L Number	Hits	Search Text	DB	Time stamp
-	1229	(soi box (silicon adj on adj insulator) (buried adj oxide)) with	USPAT;	2003/09/21 11:58
		(fet (field adj effect adj transistor))	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	4070		IBM_TDB	000040444040
-	1079	((soi box (silicon adj on adj insulator) (buried adj oxide)) with	USPAT;	2002/12/11 13:42
		(fet (field adj effect adj transistor))) and @ad<=20010425	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM_TDB	
_	900	((soi box (silicon adj on adj insulator) (buried adj oxide)) with	USPAT;	2002/12/11 13:42
		(fet (field adj effect adj transistor))) and @ad<=20000406	US-PGPUB;	2002/12/11 10:42
		(*** (***** = =, ***********************	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	311	(((soi box (silicon adj on adj insulator) (buried adj oxide)) with	USPAT;	2002/12/11 13:45
		(fet (field adj effect adj transistor))) and @ad<=20000406)	US-PGPUB;	
		and (silicide cobalt co titanium ti)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	90939	(((soi box (silicon adj on adj insulator) (buried adj oxide)) with	USPAT;	2002/12/11 13:43
		(fet (field adj effect adj transistor))) and @ad<=20000406)	US-PGPUB;	
		and (silicide cobalt co titanium ti) implant	EPO; JPO;	
			DERWENT;	
	10	///pai bay/ailian adi an adi inaylatan//bywiad adi ayida//with	IBM_TDB	00004044 40.40
-	12	(((soi box (silicon adj on adj insulator) (buried adj oxide)) with (fet (field adj effect adj transistor))) and @ad<=20000406)	USPAT; US-PGPUB;	2002/12/11 13:43
		and (silicide cobalt co titanium ti) with implant	EPO; JPO;	
		and (sincide cobait co titaliidht ti) with implant	DERWENT;	
			IBM_TDB	
-	254	(((soi box (silicon adj on adj insulator) (buried adj oxide)) with	USPAT;	2002/12/11 13:54
		(fet (field adj effect adj transistor))) and @ad<=20000406)	US-PGPUB;	
		and (silicide cobalt co titanium ti) and source and drain	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	14	((((soi box (silicon adj on adj insulator) (buried adj oxide))	USPAT;	2002/12/11 13:55
		with (fet (field adj effect adj transistor))) and •	US-PGPUB;	
		@ad<=20000406) and (silicide cobalt co titanium ti) and	EPO; JPO;	
		source and drain) and ratio with silicon	DERWENT;	
_	3	("5801084" "6096582" "6159824").PN.	IBM_TDB	2002/12/11 12:50
_	6	oki.as. and (soi with fet)	USPAT USPAT;	2002/12/11 13:58 2002/12/11 13:59
		Similar. With 100)	US-PGPUB;	2002/12/11 10:09
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2	("6190977" "6287901").PN.	USPAT	2002/12/11 14:01
-	1794	soi and fet	USPAT;	2002/12/11 14:18
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	464	(and and fath and ((anyone duality) softtle attacks	IBM_TDB	00004044444
-	161	(soi and fet) and ((source drain) with silicide)	USPAT;	2002/12/11 14:19
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM_TDB	
_	102	((soi and fet) and ((source drain) with silicide)) and	USPAT;	2002/12/11 14:24
		@ad<=20000406	US-PGPUB;	
			EPO; JPO;	
	ĺ		DERWENT;	
			IBM_TDB	

-	2	(((soi and fet) and ((source drain) with silicide)) and	USPAT;	2002/12/11 14:27
		@ad<=20000406) and silicide with ratio	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2	(((soi and fet) and ((source drain) with silicide)) and	USPAT;	2002/12/11 14:28
		@ad<=20000406) and (refractory metal) with (rich stuffed)	US-PGPUB;	
		Gad - 20000 (00) and (10) actory (110) actory	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2	(((soi box (silicon adj on adj insulator) (buried adj oxide)) with	USPAT;	2002/12/11 14:28
	_	(fet (field adj effect adj transistor))) and @ad<=20000406)	US-PGPUB:	
				1
		and (refractory metal) with (rich stuffed)	EPO; JPO;	
	l		DERWENT;	
			IBM TDB	
_	7899	(refractory metal) with (rich stuffed)	USPAT:	2002/12/11 14:28
	7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7	(Ton dotory Michael, Will (Hon Standay)	US-PGPUB;	
				,
			EPO; JPO;	
			DERWENT;	
1			IBM_TDB	· ·
1_	653	((refractory metal) with (rich stuffed)) and ((438/\$)	USPAT:	2002/12/11 14:30
_				2002/12/11 17.00
		(257/\$)).ccls.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
	71	///refreeten/metal\with/righ stuffed\\ and //429/\$\		2002/42/44 44:20
-	/ 1	(((refractory metal) with (rich stuffed)) and ((438/\$)	USPAT;	2002/12/11 14:30
		(257/\$)).ccls.) and fet	US-PGPUB;	
			EPO; JPO;	
1			DERWENT;	
			IBM_TDB	
	10	////refreeten/metall/with/righ etuffed)/ and //420/ft		2002/12/11 14:38
-	19	((((refractory metal) with (rich stuffed)) and ((438/\$)	USPAT;	2002/12/11 14.38
		(257/\$)).ccls.) and fet) and soi	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
		//!!C000040!!\ (!!C007E00!!\ -= (!!C407C04!!\ -=		0000/40/44 45:00
-	8	(("5288948") or ("6037588") or ("6197601") or	USPAT;	2002/12/11 15:06
İ		("6274470")).PN.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
·	4	6274470 LIDDNI		2002/42/44 44:40
-	1	6274470.URPN.	USPAT	2002/12/11 14:40
-	2	(drain source) with silicide and stuff\$3 with (refractory metal)	USPAT;	2002/12/11 14:42
			US-PGPUB;	
1			EPO; JPO;	
1				
			DERWENT;	
			IBM_TDB	
-	899	(drain source) with silicide and fet	USPAT;	2002/12/11 14:43
			US-PGPUB;	
1			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	161	((drain source) with silicide and fet) and soi	USPAT;	2002/12/11 14:43
		, , , , , , , , , , , , , , , , , , , ,	US-PGPUB;	
			EPO; JPO;	
1			DERWENT;	
1	1		IBM_TDB	
-	102	(((drain source) with silicide and fet) and soi) and	USPAT;	2002/12/11 14:43
	'	@ad<=20000406	US-PGPUB;	
	1			
			EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
-	7	5719083.URPN.	USPAT	2002/12/11 14:45
l _	7	5719083.URPN.	USPAT	2002/12/11 14:45
L	.1	0.10000.010.10	301 A1	2002/12/11 14.40

-	10	("3830657" "5084413" "5087296" "5094697" "5112773"	USPAT	2002/12/11 14:45
		"5177569" "5198389" "5254481" "5445982"		
		"5554566").PN.		
-	1	6274470.URPN.	USPAT	2002/12/11 14:54
-	5	("5869396" "6022457" "6025267" "6083817"	USPAT	2002/12/11 14:54
		"6274470").PN.		
_	2	6022457.ÚRPN.	USPAT	2002/12/11 14:59
	14	("4378628" "4814294" "5045496" "5047367" "5356837"	USPAT	2002/12/11 15:00
	''	"5449642" "5536684" "5567651" "5736461" "5874342"		
		"5902129" "5904564" "5989988" "6022457").PN.		
	14	((cobalt with rich) with silicide) and ((438/\$) (257/\$)).ccls.	USPAT;	2002/12/11 15:09
-	'7	((Cobait With Hell) With Silicide) and ((400/4) (207/4)).0013.	US-PGPUB;	2002/12/11 10:00
			EPO; JPO;	
			DERWENT;	
	l			
		4070000 LIDDLI	IBM_TDB	000040444544
-	64	4378628.URPN.	USPAT	2002/12/11 15:14
-	4331	((438/476) or (438/655) or (438/656) or (438/664) or	USPAT;	2002/12/13 07:25
		(438/683) or (438/685)).CCLS.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	•
			IBM_TDB	
-	521	(((438/476) or (438/655) or (438/656) or (438/664) or	USPAT;	2002/12/13 07:26
İ		(438/683) or (438/685)).CCLS.) and (cobalt)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	249	((((438/476) or (438/655) or (438/656) or (438/664) or	USPAT;	2002/12/13 07:26
		(438/683) or (438/685)).CCLS.) and (cobalt)) and (source	US-PGPUB;	
		drain) and electrode	EPO; JPO;	
		arany and ciconode	DERWENT;	
			IBM TDB	
	199	(((((438/476) or (438/655) or (438/656) or (438/664) or	USPAT;	2002/12/13 07:39
_	199	((((438/683) or (438/685)).CCLS.) and (cobalt)) and (source	•	2002/12/13 07.39
			US-PGPUB;	
		drain) and electrode) and @ad<=20000406	EPO; JPO;	
			DERWENT;	
		/////400/470) == (400/055) == (400/050) == (400/004) ==	IBM_TDB	00004040 07.00
-	0	((((((438/476) or (438/655) or (438/656) or (438/664) or	USPAT;	2002/12/13 07:39
	•	(438/683) or (438/685)).CCLS.) and (cobalt)) and (source	US-PGPUB;	
		drain) and electrode) and @ad<=20000406) and "co.sub.2si"	EPO; JPO;	
			DERWENT;	**
	1		IBM_TDB	
-	1	((((((438/476) or (438/655) or (438/656) or (438/664) or	USPAT;	2002/12/13 07:40
		(438/683) or (438/685)).CCLS.) and (cobalt)) and (source	US-PGPUB;	
		drain) and electrode) and @ad<=20000406) and cobalt with	EPO; JPO;	
		rich	DERWENT;	•
			IBM_TDB	
-	2	((((((438/476) or (438/655) or (438/656) or (438/664) or	USPAT;	2002/12/13 07:41
		(438/683) or (438/685)).CCLS.) and (cobalt)) and (source	US-PGPUB;	
1		drain) and electrode) and @ad<=20000406) and cobalt with	EPO; JPO;	
		excess	DERWENT;	
1			IBM_TDB	
-	71	((((((438/476) or (438/655) or (438/656) or (438/664) or	USPAT;	2002/12/13 08:24
		(438/683) or (438/685)).CCLS.) and (cobalt)) and (source	US-PGPUB;	
1		drain) and electrode) and @ad<=20000406) and silicide with	EPO; JPO;	
		low with resistance	DERWENT;	
			IBM_TDB	
1_	1	(((((((438/476) or (438/655) or (438/656) or (438/664) or	USPAT;	2002/12/13 08:24
	·	(438/683) or (438/685)).CCLS.) and (cobalt)) and (source	US-PGPUB;	2302/12/10 00:24
		drain) and electrode) and @ad<=20000406) and silicide with	EPO; JPO;	
		low with resistance) and (dicobalt (di adj cobalt))	DERWENT;	
!		ion man resistance, and (dicobait (di adj cobait))	IBM TDB	•
1	1.		םלו ואומי	

				· · · · · · · · · · · · · · · · · · ·
-	118	((((((438/476) or (438/655) or (438/656) or (438/664) or	USPAT;	2002/12/13 13:59
1		(438/683) or (438/685)). CCLS.) and (cobalt)) and (source	US-PGPUB;	
,		drain) and electrode) and @ad<=20000406) and low with	EPO; JPO;	
		resistance	DERWENT;	
		700101011120	IBM_TDB	i
	12	"cobalt monosilicide" and stable	USPAT;	2002/12/13 14:02
-	12	Copail monosilicide and stable	US-PGPUB;	2002/12/10 102
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	3	"cobalt monosilicide" and unstable	USPAT;	2002/12/13 14:02
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	47	"cobalt monosilicide"	USPAT:	2002/12/13 14:08
	· · ·		US-PGPUB:	
ļ			EPO; JPO;	
			DERWENT;	
1				
	4-		IBM_TDB	0000/40/44 40:40
-	47	"cobalt monosilicide"	USPAT;	2002/12/14 10:40
			US-PGPUB;	
			EPO; JPO;	
	ĺ		DERWENT;	
			IBM_TDB	
-	18	"cobalt monosilicide" and (ratio stoichiometric\$3)	USPAT;	2002/12/14 10:40
		, , , , , , , , , , , , , , , , , , ,	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	i		IBM TDB	
	1492	(soi box (silicon adj on adj insulator) (buried adj oxide) simox)	USPAT;	2003/09/21 11:58
-	1432	with (fet (field adj effect adj transistor))	US-PGPUB;	2000/00/21 11:00
		with (let (lield adj effect adj transistor))	EPO; JPO;	
				1
			DERWENT;	
	4000		IBM_TDB	0000/00/04 44:50
-	1060	(soi box (silicon adj on adj insulator) (buried adj oxide) simox)	USPAT;	2003/09/21 11:58
	1	with (fet (field adj effect adj transistor))	US-PGPUB	
-	319	((soi box (silicon adj on adj insulator) (buried adj oxide)	USPAT;	2003/09/21 12:09
	1	simox) with (fet (field adj effect adj transistor))) and silicide	US-PGPUB	
-	31	((soi box (silicon adj on adj insulator) (buried adj oxide)	USPAT;	2003/09/21 12:09
		simox) with (fet (field adj effect adj transistor))) and silicide	US-PGPUB	
		with (bottom rear)		
-	1 1	"5883396".PN.	USPAT	2003/09/21 12:55
_	i	6160293.URPN.	USPAT	2003/09/21 12:55
1_	14	("4617066" "5710450" "5965917" "6087234" "6121100"	USPAT	2003/09/21 12:55
1	'*	"6160291" "6160293" "6165826" "6274488" "6316357"	33,71	2300,00721 12.00
		0100291		
	<u> </u>	"6335253" "6380590" "6395587" "6403433").PN.		L